1 Transport properties of cubic zero-moment ferromagnetic Mn₂Ru_xGa thin ₂ films

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- (Dated: 8 December 2014)

We have studied the spin-dependent transport properties of cubic Mn_2Ru_xGa thin-films as function of the the Ru concentration, x and the substrate induced strain. We find that at Ru concentration $x \approx 0.7$, which shows practically zero magnetization, the spontaneous Hall effect at room temperature reverses sign and the spontaneous Hall angle is maximized. In addition, a small tetragonal distortion, $c/a \sim 2\%$, allows us to tune the compensation of the two Mn sub-lattices to a preferred temperature at, above or below room temperature. Having two handles on the zero moment half magnetic properties of Mn₂Ru_xGa opens up the possibilities for using this new class of material in various spintronic devices.

INTRODUCTION

Cubic ferromagnetic Heusler compounds are a family 10 of magnetic materials that often exhibit higher spin polarization at the Fermi level than binary ferromagnetic 3d₁₂ alloys¹. Some of the materials are half- metals with a gap 13 in the spin-polarized density of states for one spin band which should make them ideal candidates for spin-valves $_{15}$ or MTJs? ? ? ? . Since the prediction by van Leuken and de Groot in 1995, of a half-metallic material with two inequivalent magnetic sub-lattices whose moments cancel out?, researchers have worked on fabricating such a material. While electronic structure calculations predicted ₂₀ several such compounds²⁻⁴, fabrication of such materials had failed^{3,5}. In 2014, Kurt et. al. reported the growth of thin films of Mn₂Ru_xGa (MRG), which was identified as a zero-moment ferrimagnet with high spin polarization and showed evidence of half-metallicity⁶.

Here we report on the temperature, composition and thickness dependent transport properties of MRG, which 27 are at or near compensation point (0.6 < x < 1.1). Addition of Ru to the cubic Mn₂Ga structure provides both states (12) and electrons (8). Based on the on the empirical Slater-Pauling rules, should result in perfect compensation for Mn₂Ru_{0.5}Ga. However the addition of Ru is likely to change both the shape and position of the Mn bands leading to a more complex behaviour of the magnetic and spin-dependent transport properties. In addition the tetragonal distortion (c/a) can also affect the band structure, hence we also look at strain as a 37 possible control parameter in engineering the MRG fully 38 compensated half metallic system.

EXPERIMENTAL TECHNIQUES

MRG films of thickness 4 nm to 70 nm were grown 78 42 ing at 250 °C substrate temperature and base pressure 80 $2\theta - \theta$ x-ray diffraction (XRD). The out-of-plane lattice $_{43}$ 2 × 10⁻⁸ Torr in a Shamrock deposition system. The $_{81}$ parameter, c, is between 0.598 nm and 0.618 nm, depend-44 films were co-sputtered from a Mn2Ga target and Ru 82 ing on the Ru concentration and film thickness. We find

45 target, and the Ru composition was controlled by keep-46 ing the Mn₂Ga sputtering power fixed while varying that ₄₇ of Ru. The MRG films were capped with a $\sim 2\,\mathrm{nm}~\mathrm{Al_2O_3}$ 48 layer to prevent oxidation. The crystal structure and lattice parameters were determined by $2\theta - \theta$ and reciprocal 50 space map (RSM) scans using a BRUKER D8 diffrac- $_{51}$ tometer. In order to determine the Ru concentration x, 52 we deposited four samples with varying Mn₂Ga target 53 power along with a Ru film. The density and thickness 54 of the samples were then measured using x-ray reflectiv-55 ity. Based on the measured density and lattice param-56 eters of these 5 control samples, we establish a relation between the x-ray density and the Ru concentration x58 against which all the samples are calibrated. Magnetization measurements were made using a Quantum Design 60 superconducting quantum interference device (SQUID) 61 magnetometer. The transport measurements were con-62 ducted on unpatterned MRG films in a physical proper-63 ties measurement system (PPMS) for temperatures from 64 10 K to 400 K. The maximum applied magnetic fields, $_{65}$ $\mu_0 H$, for the two systems were 5 T and 14 T respec-66 tively. A summary of sample properties is provided in 67 Table I. We also incorporated the MRG as the hard 68 layer into a pseudo-spin-valve with the structure, MgO/ 69 MRG(15)/Cu(2.8)/[Co(0.2)/Pd(0.6)]₆ /Ta(3 nm) in or-70 der to investigate the spin dependent transport. The 71 MRG layer was grown at 250 °C, then cooled down to 72 room temperature, and was subsequently transferred to 73 a different deposition chamber for the Cu/[Co/Pd] multi-74 layer deposition. Atomic force microscopy measurements $_{75}$ of the MRG film showed a roughness of $\sim 0.2\,\mathrm{nm},$ free of 76 pinholes.

77 111. **RESULTS AND DISCUSSION**

The crystal structure of the cubic MRG films with on MgO (001) substrates by dc-magnetron sputter- 79 different thickness and compositions were probed using

TABLE I. Summary of sample properties. The temperature at which full compensation occurs, T_{comp} was defined by the temperature where $\partial \rho_{xy}/\partial T$ reaches its maximum.

Ru x	t	c/a-1	M_s	T_{comp}
	$_{ m nm}$	%	$\mu_{ m B}$	K
0.62	70	2.07	-0.09	100-200
0.69	70	1.76	0.03	200-300
0.73	70	1.83	0.07	300-360
0.77	70	1.92	0.09	> 360
1.09	70	1.82	0.07	> 360
1.12	70	1.84	0.07	387
1.01	34	1.92	-	335
0.98	16	2.24	-	280
1.09	8	2.90	-	214
1.07	4	3.60	-	< 10

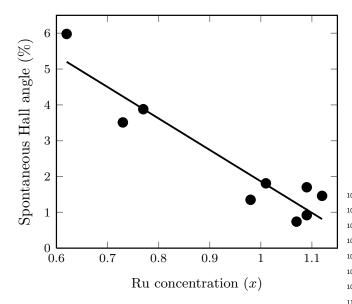


FIG. 1. Evolution of the spontaneous Hall angle (SHA) as a function of Ru composition, x, extracted from SHE measurements. The solid line is a linear fit of the data set.

84 ness. The in-plane lattice parameter, a, determined from 117 strongly on the lattice distortion since this would have 85 reciprocal space maps was found to be 0.596 nm for all 118 an effect on the interaction between neighbouring atoms. samples, which is precisely matched to that of the MgO 119 We prepared MRG samples of different thickness from $_{91}$ anisotropy in all the samples we have studied. A small $_{124}$ be seen that the coercivity diverges to $\sim 9\,\mathrm{T}$ at $350\,\mathrm{K}$ 92 soft in-plane component is also present. As the Ru con- 125 and the sign of the SHE loop reverses at 300 K. This in- $_{93}$ centration is reduced from x=1.09, the magnetization $_{126}$ dicates that the compensation temperature lies between 94 reduces, until it falls practically to zero (12 kA/m or 127 300 K and 350 K. By plotting the derivative of the Hall ₉₅ 0.07 $\mu_{\rm B}$ f.u.⁻¹) at x=0.68. We can attribute this to the ₁₂₈ resistance w.r.t temperature, $\delta R_{XY}/\delta T$, as shown in Fig. ₉₆ almost perfect compensation of the two Mn sub-lattices ₁₂₉ 3(a), it can be seen that this compensation temperature 97 at room temperature. 98 the magnetization again increases, coincident with the 131 is reduced. It is worth noting that the compensation 99 reversal in sign in the room temperature spontaneous 132 temperature varies with both the Ru content and strain. 100 Hall effect (SHE) measurements. From the SHE mea- 133 Since the compensation is achieved by the cancelling out 101 surements with varying Ru content, we extracted the 134 of the moment of the two inequivalent Mn sub-lattices, 102 coercivity, $\mu_0 H_c$, and spontaneous Hall angle (SHA) (135 this shift in compensation temperature may be due to

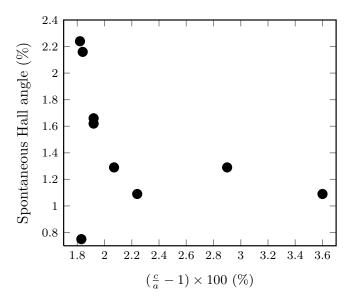


FIG. 2. Evolution of the spontaneous Hall angle (SHA) as a function of c/a ratio extracted from SHE measurements for samples with their SHA translated to a virtual x = 1.0 Ru concentration.

defined as ρ_H/ρ (Fig. ??(b)). As the magnetization 104 approaches zero the coercivity clearly diverges (the 105 sample closest to compensation at room temperature 106 could not be saturated at an applied field of 5 T). The 107 recorded SHA for samples near compensation ($\sim 5\%$) 108 are about a magnitude larger than those reported for 109 other 3d ferromagnets at room temperature (0.2 to $110 \ 0.3\%$)⁷ and comparable to SHA recorded for amorphous 111 rare earth transition metal alloys⁸. A high SHA is 112 indicative of much lower carrier concentrations and a 113 high spin polarization.

As shown in Fig. ??, the MRG films are increas-115 ingly strained as the thickness of the film is reduced. It 83 that c increases exponentially with reducing film thick- 116 has been predicted that the magnetization may depend substrate ($\sqrt{2}a_0$ (MgO) = 0.5956 nm). This confirms the $_{120}$ 70 nm down to 4 nm and measured their SHE response cubic nature of the MRG films with a slight tetragonal $_{\rm 121}$ at different temperatures from 400 K to 4 K in the PPMS. out-of-plane distortion (c/a-1 between 1.8% and 3.6%). 122 Fig. ??(b) shows a typical SHE response over the tem-SQUID magnetometry shows clear out-of-plane 123 perature range for the sample of 34 nm thickness. It can On further reduction of Ru 130 shifts to lower temperatures as the thickness of the MRG

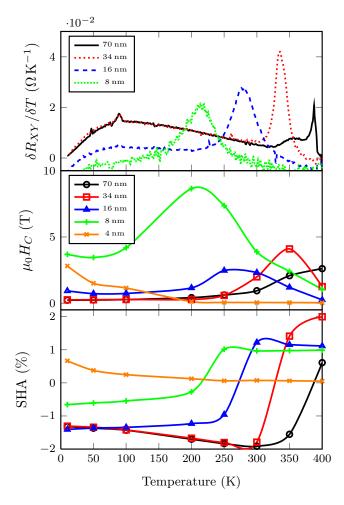


FIG. 3. (a) Variation of compensation temperature with the thickness of MRG film of same Ru concentration, given by the derivative of the resistance w.r.t temperature. The compensation temperature shifts to lower temperatures with decreasing thickness. (b) Extracted coercive field and (c) spontaneous Hall angle as a function of temperature for samples with the same Ru concentration ($x \sim 1.0$) and various thickness from $70 \, \mathrm{nm}$ to $4 \, \mathrm{nm}$.

136 the slightly different temperature dependence of the two $_{137}$ sub-lattices. As with samples with different Ru content, $_{182}$ 138 the extracted coercivity and SHA show maximum values 183 9I. Galanakis, K. Özdoğan, E. Şaşıoğlu, and S. Blügel, Journal of 139 near the compensation temperature for each thickness as 184 Applied Physics 116, 033903 (2014).

140 shown in Fig. 3(b) and (c) respectively.

141 IV. CONCLUSION

We have shown above that the spin-dependent transport properties of Mn₂Ru_xGa are tuneable with both $_{144}$ the Ru concentration x and strain. Recent ab inito calculations⁹ while providing some insight into the electronic structure, does not give convincing arguments explaining the variation of the transport properties both with varying Ru concentration x and strain. Above we have shown that for a Ru concentration $x \approx 0.7$, which shows practically zero magnetization, the sign of the spontaneous Hall effect is reversed, indicating the rever-152 sal of the majority spin channel. Concurrently the spon-153 taneous Hall angle is maximised which would imply a 154 reduction in the carrier concentration and high spin po-155 larisation that point towards a half metallic state. We 156 also show that by varying the tetragonal distortion at a 157 particular Ru composition, we can tune the compensa-158 tion of the two Mn sub lattices to be at a relavant tem-159 perature regime at above or below room temperature.

ACKNOWLEDGEMENTS

This work was supported by Science Foundation Ire-162 land through AMBER, and from grant 13/ERC/I2561. 163 KR acknowledges financial support from the European Community's Seventh Framework Programme IFOX, NMP3-LA-2010-246102. DB acknowledges financial sup-166 port from IRCSET. The authors would like to thank H. 167 Kurt, M. Zic and T. Archer for fruitful discussions.

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